ZNI1000 Temperature sensor

Description

The ZNI1000 is a Ni thin film Resistance Temperature Detector (RTD), specified to DIN 43760. The high temperature coefficient offers higher signal outputs than other RTD's, which results in higher accuracy with smaller temperature changes.

Features

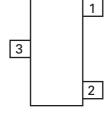
- Resistance at 0°C: 1000
- Nickel temperature detector
- Specified to DIN 43760
- SOT23 package

Applications

- Automotive electronic
- Circuit protection
- Temperature compensation
- Temperature measurement

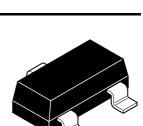
Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel	Device marking
ZNI1000TA	7	8	3,000	ZNI
ZNI1000TC	13	8	10,000	ZNI



Pinout - top view

Pin 1 - Ni1000 Pin 2 - Ni1000 Pin 3 - Need a good thermal contact for short response time





Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Continuous current ^(a)	I _{CC}	5	mA
Total power dissipation	P _{TOT}	20	mW
Operating temperature range	T _A	-55 to +150	°C
Storage temperature range	T _{stg}	-55 to +150	°C

NOTES:

(a) Limited by operating temperature [$I_{CC}{\leq}(20mW/R)^{\frac{1}{2}}$, R=func(T_A)=718 to 1986\Omega].

Recommended operating conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
I _{MDC}	Steady state measurement current ^(b)	0,1	1,2	3,0	mA

NOTES:

(b) limited by self heating effects (recommended current range 0,1 to 1,5mA)

[typ. case \rightarrow temperature error Δ T= (R·1,2mA·1,2mA)/1,7mW/K \leq 1,7K]

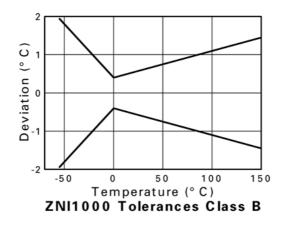
[worst case → temperature error ΔT = (1,986k Ω ·3,0mA·3,0mA)/1,4mW/K = 13,8K].

Electrical characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
R0	Resistance 0°C	T=0°C, I _M <1mA	-	1000	-	Ω
R25	Resistance 25°C	T=25°C, $I_M = 3mA^{(c)}$	1100	1141	1200	Ω
R100	Resistance 100°C	T=100°C, I _M <1mA	-	1618	-	Ω
	Tolerance class B ^(d)	-55 to 0°C	-	±(0.4+0.028 x ¦T¦)	-	°C
	Tolerance class B ^(d)	0 to 150°C	-	±(0.4+0.007 x ¦T¦)	-	°C
ΔR	Long Term stability:	1000h at 150°C		0.1		%

NOTES:

(c) Measured under pulse conditions.(d) See ZNi1000 Tolerance class figure.



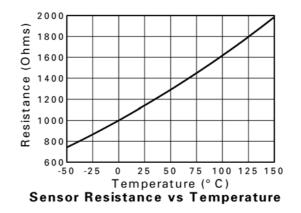
Characteristics according to DIN43760

Resistance at a given temperature

R0	Resistance at 0°C	В	6.650 x 10 ⁻⁶
Т	Temperature in °C	С	2.805 x 10 ⁻¹¹

А	5.485 x 10 ⁻³	D	-2.000 x 10 ⁻¹⁷

$$R(T) = R0 \times (1 + A \times T + B \times T^{2} + C \times T^{4} + D \times T^{6})$$



Formula for temperature at a given resistance

 $T(R) = A + B \times \sqrt{1 + C \times R} + D \times R^{5} + E \times R^{7}$ coefficients: A = -412.6B = 140.41C = 0.00764 $D = -6.25 \times 10^{-17}$ $E = -1.25 \times 10^{-24}$

Self heating

For accurate temperature measurement it's recommended to choose a small current in order to avoid self heating of the resistor. The temperature failure caused by the measurement current can be calculated with:

$$\Delta \mathsf{T}=\mathsf{P}/\mathsf{E}\mathsf{K}$$

where $P = I^2 * R$ is the heat power caused by the measurement current and EK is the self heating coefficient.

The self heating coefficient for the Ni1000-SOT is:

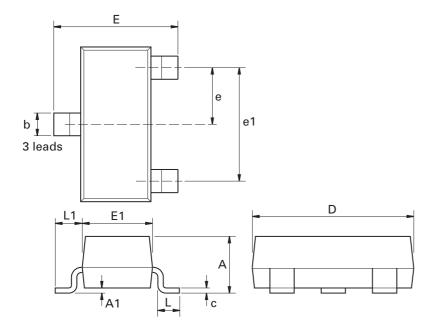
 $EK = (1.7 \pm 0.3) \text{ mW/K}$ (Air: 23°C; no air flow).

₽° C | DVM 1V-->100'C 0,2V-->20'C 0 Application of the nickel sensor ZNI 1000 500 680 1,5k ≒ 11 100n OUT 1,5k ZMR500 (5V) GND +ZNI1000 t° Ζ (1k) 10u + 100n

ZNI1000

+15V

Package outline - SOT23



Dim.	Millin	neters	Inc	hes	Dim.	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90	NOM	0.075	NOM
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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